## NSN 5961-00-939-4226



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-939-4226 **Inclosure Material:** Metal **Overall Length:** 0.575 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.355 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.375 inches **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 3.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 100.00 milliamperes source cutoff current and 700.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 6.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

Demilitarization:

**Unit Of Measure:** 

No

## **NSN 5961-00-939-4226** Transistor - Page 2 of 2



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